NSN 5962-01-291-5581

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View Online at https://aerobasegroup.com/nsn/5962-01-291-5581

Body Length:
Between 0.442 inches and 0.458 inches
Body Width:
Between 0.442 inches and 0.458 inches
Body Height:
Between 0.064 inches and 0.100 inches
Maximum Power Dissipation Rating:
1.155 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Monolithic and bipolar and hermetically sealed and w/enable
Inclosure Material:
Ceramic
Inclosure Configuration:
Leadless flat pack
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
14 input
Case Outline Source And Designator:
C-4 mil-m-38510
Current Rating Per Characteristic:
30.00 milliamperes forward current, nonrepetitive, peak total value absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Time Rating Per Chacteristic:
30.00 nanoseconds propagation delay time, low to high level output and 30.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Ram
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:

Unit Of Measure:

N/a

28 leadless **Shelf Life:**

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Demilitarization:

Yes - demil/mli

Fiig:

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